

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	1765	257/191.ccls. 257/197.ccls. 257/198.ccls. 257/201.ccls. 257/592.ccls.	US-PGPUB; USPAT	OR	OFF	2004/11/18 10:43
L2	99	1 and (bismuth bi gaasbi gaasbin inpbi)	US-PGPUB; USPAT	OR	ON	2004/11/18 15:30
L3	1353	(hbt (heterojunction adj bipolar) (bipolar near2 transistor) (emitter same base same collector)) same (bismuth bi gaasbi gaasbin inpbi)	US-PGPUB; USPAT	OR	ON	2004/11/18 12:54
L4	90	(hbt (heterojunction adj bipolar)) same (bismuth bi gaasbi gaasbin inpbi)	US-PGPUB; USPAT	OR	ON	2004/11/18 13:04
L5	1	(hbt (heterojunction adj bipolar) (bipolar near2 transistor) (emitter same base same collector)) same (gaasbi gaasbin inpbi)	US-PGPUB; USPAT	OR	ON	2004/11/18 10:49
L6	5	(hbt (heterojunction adj bipolar)) same (((bismuth bi) with (contain\$6 dop\$6 implant\$6 additive)) gaasbi gaasbin inpbi)	US-PGPUB; USPAT	OR	ON	2004/11/18 13:33
L7	106	(hbt (heterojunction adj bipolar) (bipolar near2 transistor) (emitter same base same collector)) same (((bismuth bi) with (contain\$6 dop\$6 implant\$6 additive impurity)) gaasbi gaasbin inpbi)	US-PGPUB; USPAT	OR	ON	2004/11/18 13:53
L8	101	(hbt (heterojunction adj bipolar) (bipolar near2 transistor) (emitter same base same collector)) and (((bismuth bi) with (contain\$4 dop\$4 implant\$6 additive impurity)) gaasbi gaasbin inpbi)	EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/18 15:19
L9	14	(hbt (heterojunction adj bipolar) (bipolar near2 transistor) (emitter same base same collector)) same (bismuth gaasbi gaasbin inpbi)	US-PGPUB; USPAT	OR	ON	2004/11/18 12:54
L10	2	jp-2002134524-\$.did.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2004/11/18 15:13
L11	30	(hbt (heterojunction adj bipolar) (bipolar near2 transistor) (emitter same base same collector)) and (bismuth gaasbi gaasbin inpbi)	EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/18 15:20

L12	5	(gaasbi gaasbin inpbi)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/18 15:30
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